Introduction

This application note describes how to tune the HSE for RF applications using STM32WB and STM32WL Series microcontrollers (hereinafter referred to as STM32 wireless MCUs). These products offer a cost-effective and efficient solution by using their internal load capacitances to control the oscillator accuracy, thus saving the cost of external capacitances, and lowering the crystal constraints.

STM32 wireless MCUs use an external oscillator high-speed clock source as the base for RF clock generation. HSE accuracy is essential for RF system performance, and the external oscillator is therefore fine-tuned to achieve the highest clock accuracy.

The first part of the document introduces the crystal oscillator solutions. The second part introduces and then compares three HSE frequency tuning methods, namely a manual one, an automatic one, and another one based on STM32CubeMonitor-RF (for the STM32WB Series only). The application of these methods to STM32WB and STM32WL Nucleo boards is described in the following sections, and provided as firmware and script examples in X-CUBE-CLKTRIM, an STM32Cube Expansion Package.

A specific section is dedicated to describe how to configure the HSE, to make its startup phase reliable and optimized for STM32WB Series microcontrollers.

This document must be read in conjunction with the reference manuals and datasheets available at www.st.com.
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1 HSE oscillator

RF systems require high frequency accuracy to achieve the best performance. Any clock deviation can cause system malfunctions and/or degrade performance.

*Table 1* shows the accuracy requirements for two RF protocols supported by STM32WB Series microcontrollers. For other protocols and standards, refer to the corresponding specifications.

<table>
<thead>
<tr>
<th>RF standard</th>
<th>Carrier accuracy</th>
</tr>
</thead>
<tbody>
<tr>
<td>Bluetooth® Low Energy</td>
<td>± 50 ppm</td>
</tr>
<tr>
<td>IEEE 802.15.4 / Thread</td>
<td>± 40 ppm</td>
</tr>
</tbody>
</table>

In STM32 wireless MCUs, based on Arm® Cortex® cores, the RF clock is provided by a high frequency VCO, which takes as reference a signal created by an embedded oscillator that uses an external crystal.

This crystal is the HSE (high-speed external) clock source of the RF synthesizer and of the microcontroller. Its nominal frequency can vary, depending on factors such as process variations, used crystal, and PCB design. The HSE inaccuracy is directly transferred to the RF clock, hence it must be fine-tuned by adjusting load capacitance at crystal terminals.

STM32 wireless MCUs offer an efficient architecture with internal load capacitances, which allows the users to fine tune the crystal frequency, without extra cost for additional external capacitances.

The reliability of the startup phase of the oscillator depends upon its actual implementation (associated crystal, external components, environment). For the STM32WB Series, a method is proposed to adjust its internal operation, to optimize and consolidate this phase. A longer startup improves reliability but increases power consumption.

*Note:* AN2867 (*Oscillator design guide for ST microcontrollers*), which generally describes HSE for STM32 products, does not apply to STM32 wireless MCUs because of RF constraints. This document is the correct reference for these products.

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a. Arm is a registered trademark of Arm Limited (or its subsidiaries) in the US and/or elsewhere.
1.1 Crystal oscillator

*Figure 1* shows the principle of the crystal oscillator system. An oscillator consists of an inverting amplifier, a feedback resistor (R\textsubscript{f}), a crystal (XTAL), and two load capacitors (C\textsubscript{L1} and C\textsubscript{L2}). C\textsubscript{s} is the stray (parasitic) capacitance, resulting from the sum of the MCU pin capacitances (between OSC\_IN and OSC\_OUT). This value is negligible, it is not necessary to know it exactly, because trimming and startup optimization procedures do not rely on it.

**Figure 1. Crystal oscillator principle**

C\textsubscript{L} load capacitance

The load capacitance is the terminal capacitance of the circuit connected to the crystal oscillator. This value is determined by the external capacitors C\textsubscript{L1} and C\textsubscript{L2}, and the stray capacitance of the printed circuit board and connections (C\textsubscript{s}). The C\textsubscript{L} value is specified by the crystal manufacturer. For the frequency to be accurate, the oscillator circuit must show to the crystal the same load capacitance as the one the crystal was adjusted for.

Frequency stability mainly requires that the load capacitance be constant. The external trimming capacitors C\textsubscript{L1} and C\textsubscript{L2} are used to tune the desired value of C\textsubscript{L} to reach the value specified by the crystal manufacturer.

The following equation gives the expression of C\textsubscript{L}

**Equation 1: Load capacitance**

\[
C_L = \frac{C_{L1} \times C_{L2}}{C_{L1} + C_{L2}} + C_s
\]
1.2 **STM32 wireless MCUs architecture**

These MCUs embed an efficient and cost-effective crystal oscillator system with internal capacitances for trimming. The advantages of the internal mechanism for load capacitance tuning are twofold:

- it reduces the accuracy constraints on the external crystal
- it reduces the global BOM (and the footprint) of the PCB.

*Figure 2* shows the crystal oscillator system embedded in the STM32 wireless MCUs. The crystal is the only external component. No extra load capacitances are needed.

*Figure 2. Crystal oscillator system overview*

The crystal oscillator system consists of two pads (OSC_IN and OSC_OUT) with their respective capacitance banks, and the amplifier stage.

For the STM32WB Series, the capacitance value is the same for both the IN and the OUT banks. This value, alongside with the oscillator gain and sense (the parameters that make possible the optimization of the startup phase), is driven by a register and controls the system behavior. These parameters are explained in *Section 1.3*.

For the STM32WL Series, the capacitance values for the IN and the OUT banks are independent. These two values are driven by two sub-GHz radio registers and control the system behavior. These parameters are explained in *Section 1.4*. 

---

**Figure 2** shows the crystal oscillator system embedded in the STM32 wireless MCUs. The crystal is the only external component. No extra load capacitances are needed.
1.3 HSE configuration parameters - STM32WB Series

Three parameters can be set to control the oscillator module. They are accessible in the RCC_HSECR register described below.

**RCC_HSECR**

**Address** 0x09C  
**Reset** 0x0000 0030  
**Access** This register is protected to avoid on-the-fly modification. A key (0xCAFECAFE) must be written at the register address to unlock it before any single write access, it is then locked again. The HSE clock must be switched off during register access procedure to avoid unpredictable behavior. Note that HSE must not be used as CPU clock source during this step. In this document the default MSI clock is used as system clock source after startup from Reset.

<table>
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<td>rw</td>
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<td>rw</td>
<td>rw</td>
</tr>
</tbody>
</table>

**Load capacitance: HSETUNE[5:0]**

This is the parameter responsible for the clock accuracy. It selects the capacitance value added on both input and output pads. The adjustable range is set to have a global load capacitance from 12 to 16 pf. The minimum (0x00) and maximum (0x3F) values correspond, respectively, to the smallest and to the largest load capacitance.

Default value is 0x00 (minimum load capacitance).

**Current control: HSEGMC[2:0]**

This parameter (referred to as Gm or Gm_crit_max in the documentation of other STM32 products for which it has a fixed value) is the maximum critical crystal transconductance of the oscillator. It controls the startup performance of the system, and its value must be greater than \( g_{\text{mcrit}} \) (see Section 8). A low value decreases the power consumption, while a high value improves the startup time.

The minimum value (0b000) corresponds to Gm = 0.18 mA/V, the maximum value (0b111) to Gm = 2.84 mA/V. Default value is 0x3 (Gm = 1.13 mA/V).

**HSES sense amplifier threshold**

This parameter controls an internal comparison threshold for the oscillator startup. When this bit is set (1), the startup time is reduced (from around 15 µs), but the current consumption is higher.

Default value is 0x0 (1/2 ratio).
1.4 HSE configuration parameters - STM32WL Series

For the STM32WL Series two parameters can be set to control the oscillator module. They are accessible in the SUBGHZ_HSEINTRIMR and the SUBGHZ_HSEOUTTRIMR sub-GHz radio registers, which contain the capacitance value of the IN and OUT banks, respectively. The associated value is represented by their six lower bits (the remaining bits of these registers must be kept at their reset values).

For both registers:
- 0x00 corresponds to the minimum capacitance (~11.3 pF)
- 0x2F corresponds to the maximum capacitance (~33.4 pF)
- the values must not exceed 0x2F, and the trimming step is ~0.47 pF
- the reset value is 0x12, which corresponds to ~20.3 pF.

As mentioned earlier, SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR are part of the sub-GHz radio and not of the system CPU. To modify their values, the user code must communicate with the sub-GHz radio via its SPI interface. The addresses of these registers, considering this SPI interface, are 0x911 for SUBGHZ_HSEINTRIMR and 0x912 for SUBGHZ_HSEOUTTRIMR.

1.5 Board implementation

Oscillator pads are available on different pins (named OSC_IN and OSC_OUT), depending upon the package. Table 2 shows the pin numbers for different packages used in Nucleo and USB dongle boards for the STM32WB Series.

Table 2. Oscillator pin numbers for the STM32WB Series

<table>
<thead>
<tr>
<th>Package</th>
<th>OSC_IN</th>
<th>OSC_OUT</th>
</tr>
</thead>
<tbody>
<tr>
<td>UFQFPN48</td>
<td>25</td>
<td>24</td>
</tr>
<tr>
<td>WLCSP49</td>
<td>F1</td>
<td>F2</td>
</tr>
<tr>
<td>VFQFPN68</td>
<td>35</td>
<td>34</td>
</tr>
<tr>
<td>WLCSP100</td>
<td>J1</td>
<td>J2</td>
</tr>
<tr>
<td>BGA129</td>
<td>M13</td>
<td>N13</td>
</tr>
</tbody>
</table>

The crystal is plugged directly onto the pads, with no extra capacitance, and as close as possible to the device, to minimize parasitic capacitance.

Figure 3 shows a typical UFQFPN48 footprint for the STM32WB Series.
The PCB layout for the STM32WB and STM32WL Series reference designs are detailed, respectively, in AN5165 "Development of RF hardware using STM32WB microcontrollers", and AN5407 "Optimized RF board layout for STM32WL Series", both available on www.st.com.

1.6 Crystal references

Table 3 shows the specification of the crystals used to validate the reference designs.

<table>
<thead>
<tr>
<th>Series</th>
<th>NDK crystal</th>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>STM32WB</td>
<td>NX2016SA 32 MHz EXS00A-CS06654</td>
<td>Load capacitance</td>
<td>8 pF</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Frequency tolerance</td>
<td>(25 ± 3 °C) ± 10 × 10⁻⁶</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Frequency vs. temperature (with reference to +25 °C)</td>
<td>± 25 × 10⁻⁶</td>
</tr>
<tr>
<td>STM32WL</td>
<td>NX2016SA 32 MHz EXS00A-CS06465</td>
<td>Load capacitance</td>
<td>10 pF</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Frequency tolerance</td>
<td>± 10 ppm at 25 °C</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Frequency vs. temperature</td>
<td>± 10 ppm (-25 to +70 °C)</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>± 30 ppm (-40 to +85 °C)</td>
</tr>
</tbody>
</table>
It is possible to use other crystals, as long as they respect the carrier accuracy requirements (see Table 1). More precisely, the sum of the maximum values for the following parameters of the chosen crystal must be below the carrier accuracy requirements:

- frequency tolerance
- frequency versus temperature characteristics (for the range in which the crystal must be used)
- aging (for the duration during which the crystal must be used).

**Note:** Such data can be named differently or absent in the crystal documentation.

The previous verification is reliable if the PCB based on the chosen crystal is designed with the requirements mentioned in Section 1.5, and fine-tuned with one of the HSE trimming methods described in the next sections of this document.

Note that the accuracy of the capacitance bank used for the HSE trimming can vary from a product to another. If the carrier accuracy verification is needed for the whole production chain, refer to Section 1.7.

### 1.7 Tuning in production

It is important to know if the trimming parameters defined for a test PCB have the same efficiency when applied to all the PCBs to be produced.

To have a faster and more efficient production chain, it is not mandatory to operate the trimming process on each PCB.

Data gathered during the production of the STM32WB Nucleo boards have shown some variations of the HSE frequency for a fixed HSETUNE value (HSETUNE accuracy). Besides, the typical HSETUNE granularity is 1 ppm (see XOTUNE granularity in STM32WB datasheets). To compensate for these variations, the following trimming method is suggested for production:

1. tune some PCBs (not more than a few dozens), to get a significant span of HSETUNE values
2. calculate the median of the found values, and use the result to trim all other PCBs
3. the interval between the median and the maximum/minimum of the found values corresponds to the HSETUNE accuracy for the tuned design.

After having followed this process, a potential frequency deviation due to the HSETUNE accuracy (point 3) must be taken into account, and added to the carrier accuracy verification calculation presented in Section 1.6.

A similar method can be used for the STM32WL Series. The number of test boards must be larger, because of the two trimming parameters for these products.
Trimming methods comparison

The three trimming methods described in this document are detailed in Table 4, and compared in Table 5.

<table>
<thead>
<tr>
<th>Method</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>Manual</td>
<td>A precision frequency meter is used to measure the HSE frequency output on one of the STM32 pins. Then, the user tunes the HSE frequency with the buttons of a Nucleo board. A button is dedicated to the saving of the tuning parameters in the STM32 nonvolatile memory.</td>
</tr>
<tr>
<td>Automatic</td>
<td>One STM32 timer is clocked with a precision external clock source provided by the user via one of the STM32 pins. This reference clock allows the user to measure the internal STM32 system HSE frequency. Then, the STM32 can compare the frequency measured with the one expected, to test and determine the best tuning parameters. Finally, the STM32 saves these parameters in its nonvolatile memory.</td>
</tr>
<tr>
<td>STM32CubeMonitor-RF(1)</td>
<td>A precision frequency meter is used to measure the HSE frequency output on one of the STM32 pins. Then, the user tunes the HSE frequency with a script to run in STM32CubeMonitor-RF. The user has to change the tuning parameter values in the script to test them. When the correct values are found, another script saves them in the STM32 nonvolatile memory.</td>
</tr>
</tbody>
</table>

1. Compatible with STM32WB Series only.

<table>
<thead>
<tr>
<th>Method</th>
<th>Advantages</th>
<th>Disadvantages</th>
</tr>
</thead>
<tbody>
<tr>
<td>Manual</td>
<td>Runs in SRAM (user program in flash memory is not affected).</td>
<td>Needs the use of buttons and a frequency meter for each product.</td>
</tr>
<tr>
<td>Automatic</td>
<td>Runs in SRAM (user program in flash memory is not affected). The user must set up a reference clock only once, to trim as many devices as wanted.</td>
<td>Method based on a more complex principle.</td>
</tr>
<tr>
<td>STM32CubeMonitor-RF(1)</td>
<td>Convenient for users familiar with STM32CubeMonitor-RF, willing to achieve the maximum functionality.</td>
<td>BLE stack and transparent mode FW must be flashed in the device. Requires several actions from the user for each product (modifying and running the script, use of a frequency meter).</td>
</tr>
</tbody>
</table>

1. Compatible with STM32WB Series only.

Note: The proposed methods require the use of a pin (MCO) to output the HSE signal for the frequency measurement. If no MCO pin is available for this purpose, AN5378 (available on www.st.com) describes another technique: instead of measuring the frequency on the MCO pin, it proposes to perform it on a tone frequency emitted by the STM32WB radio. However,
while this tone is emitted, HSE cannot be trimmed, because it is used by the radio (actually this is more a verification than a real trimming method, like those exposed in this document).
3 Manual frequency trimming procedure example for the STM32WB Series

The firmware and scripts associated to this document are available as an STM32Cube Expansion Package (X-CUBE-CLKTRIM_vx.y\Projects\P-NUCLEO-WB55.Nucleo\RCC_HSE_Calib).

3.1 Procedure description

The procedure consists in measuring the HSE clock generated inside the device from the external crystal. This clock is output on pin PA8 and is measured by a precision frequency meter.

*Note:* An external reference is mandatory since no such accurate one is integrated in the device.

A step-by-step tuning of the load capacitance is performed to reach the best accuracy of the HSE clock. The load capacitance value is then stored inside a nonvolatile location of the device, either a dedicated area of the user flash memory or in the One-Time-Programming (OTP) area.

Flash memory or OTP programming is done with a double-word granularity (64 bits). To save OTP bytes (1 K in the STM32WB Series), the load capacitance value on six bits can be appended to a 64-bit wide structure with other personalization data (such as Bluetooth® device address, MAC short address, product specific code, key).

This procedure can be done several times, only the latest setup is active.

Once the procedure is completed, the active load capacitance value can be retrieved at startup (in the clock configuration function), and the HSE configuration register set accordingly.

3.2 Implementation

The procedure is executed in SRAM, so it can be run on an already programmed device, without modifying the flash memory content.
3.2.1 Hardware setup

Figure 4 shows the manual calibration procedure for a STM32WB Series Nucleo-68 board.

Figure 4. Manual calibration overview - STM32WB Series

A precision frequency meter (better than 0.1 ppm) must be connected to pin PA8/MCO, and set to detect a 32 MHz 3.3 V square wave peak to peak signal.

Note: Standard oscilloscopes are not sufficiently accurate for this kind of measurement.

Boot from SRAM

Boot selection can be done through the BOOT0 pin and nBOOT1 bit in the User options (FLASH_OPTR).

The boot from SRAM configuration is set by both Boot0 = 1 and nBoot1 = 0 conditions, nBoot1 is set only by option bit FLASH_OPTR[23].

Boot0 can be selected

- through value of pin PH3 at startup if option bit nSWBOOT0 = 1 (FLASH_OPTR[26] = 1), see the option byte panel in Figure 5
- through option bit value nBOOT0 if option bit nSWBOOT0 = 0 (FLASH_OPTR[26] = 0), see the option byte panel in Figure 6

Option bits can be selected through STM32CubeProgrammer.
Figure 5. OB configuration to boot from SRAM with BOOT0 value driven by PH3 pin

<table>
<thead>
<tr>
<th>Name</th>
<th>Value</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>nBOOT0</td>
<td></td>
<td>Unchecked: &amp;BOOT0=0 Boot selected based on &amp;BOOT1. Checked: &amp;BOOT0=1 Boot from main Flash</td>
</tr>
<tr>
<td>nBOOT1</td>
<td></td>
<td>Unchecked: Boot from code area if &amp;BOOT0=0 or otherwise embedded SRAM. Checked: Boot from code area if &amp;BOOT0=1 otherwise system flash</td>
</tr>
<tr>
<td>nWRBOOT1</td>
<td></td>
<td>Unchecked: BOOT0 taken from the option bit nWRBOOT1. Checked: BOOT0 taken from PH3/BOOT0 pin</td>
</tr>
<tr>
<td>SREABST</td>
<td></td>
<td>Unchecked: SREABST word will never reset account. Checked: SREABST is not erased when a system reset occurs</td>
</tr>
<tr>
<td>SRA9YF</td>
<td></td>
<td>Unchecked: SRA9YF party check model. Checked: SRA9YF party check disabled</td>
</tr>
<tr>
<td>nAP_SRP</td>
<td></td>
<td>Unchecked: Reset generated when entering the Stop mode. Checked: No reset generated when entering the Stop mode</td>
</tr>
<tr>
<td>nAP_SDP</td>
<td></td>
<td>Unchecked: Reset generated when entering the Standby mode. Checked: No reset generated when entering the Standby mode</td>
</tr>
<tr>
<td>nAP_SCRX</td>
<td></td>
<td>Unchecked: Reset generated when entering the Shutdown mode. Checked: No reset generated when entering the Shutdown mode</td>
</tr>
<tr>
<td>nSRCCS</td>
<td></td>
<td>Unchecked: Hardware window watching. Checked: Software window watching</td>
</tr>
<tr>
<td>nAP_SCRN</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Standby mode. Checked: Independent watchdog counter running in Standby mode</td>
</tr>
<tr>
<td>nAP_SRSTP</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Stop mode. Checked: Independent watchdog counter running in Stop mode</td>
</tr>
<tr>
<td>nAP_SRSTC</td>
<td></td>
<td>Unchecked: Independent watchdog. Checked: Software independent watchdog</td>
</tr>
<tr>
<td>nAP_SRSTB</td>
<td></td>
<td>Unchecked: Software independent watchdog. Checked: Software independent watchdog</td>
</tr>
<tr>
<td>BUSCLKA</td>
<td></td>
<td>Unchecked: IPC revision data buffer base address</td>
</tr>
</tbody>
</table>

Figure 6. OB configuration to boot from SRAM with BOOT0 value driven by option bit nBOOT0

<table>
<thead>
<tr>
<th>Name</th>
<th>Value</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>nBRST0</td>
<td></td>
<td>Unchecked: &amp;BRST0=0 Boot selected based on &amp;BRST1. Checked: &amp;BRST0=1 Boot from main Flash</td>
</tr>
<tr>
<td>nBRST1</td>
<td></td>
<td>Unchecked: Boot from code area if &amp;BRST0=0 or otherwise embedded SRAM. Checked: Boot from code area if &amp;BRST0=1 otherwise system flash</td>
</tr>
<tr>
<td>nWRBRST1</td>
<td></td>
<td>Unchecked: BRST0 taken from the option bit nWRBRST1. Checked: BRST0 taken from PH3/BRST0 pin</td>
</tr>
<tr>
<td>SREBRST</td>
<td></td>
<td>Unchecked: SREBRST word will never reset account. Checked: SREBRST is not erased when a system reset occurs</td>
</tr>
<tr>
<td>SRA9YF</td>
<td></td>
<td>Unchecked: SRA9YF party check model. Checked: SRA9YF party check disabled</td>
</tr>
<tr>
<td>nAP_SRP</td>
<td></td>
<td>Unchecked: Reset generated when entering the Stop mode. Checked: No reset generated when entering the Stop mode</td>
</tr>
<tr>
<td>nAP_SDP</td>
<td></td>
<td>Unchecked: Reset generated when entering the Standby mode. Checked: No reset generated when entering the Standby mode</td>
</tr>
<tr>
<td>nAP_SCRX</td>
<td></td>
<td>Unchecked: Reset generated when entering the Shutdown mode. Checked: No reset generated when entering the Shutdown mode</td>
</tr>
<tr>
<td>nSRCCS</td>
<td></td>
<td>Unchecked: Hardware window watching. Checked: Software window watching</td>
</tr>
<tr>
<td>nAP_SCRN</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Standby mode. Checked: Independent watchdog counter running in Standby mode</td>
</tr>
<tr>
<td>nAP_SRSTP</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Stop mode. Checked: Independent watchdog counter running in Stop mode</td>
</tr>
<tr>
<td>nAP_SRSTC</td>
<td></td>
<td>Unchecked: Independent watchdog. Checked: Software independent watchdog</td>
</tr>
<tr>
<td>nAP_SRSTB</td>
<td></td>
<td>Unchecked: Software independent watchdog. Checked: Software independent watchdog</td>
</tr>
<tr>
<td>BUSCLKA</td>
<td></td>
<td>Unchecked: IPC revision data buffer base address</td>
</tr>
</tbody>
</table>
Clock output

HSE clock is output on the pin PA8 (MCO), which is available on connectors CN9/D6 and CN10/25. PA8 configuration is performed in the firmware. Frequency meter probe is connected to one of these connectors and ground can be taken from connector CN11 or CN12. According to the type of frequency meter used, AC coupling instead of DC may be needed.

The next sequence is required to output the HSE on the MCO pin.

1. Turn on the HSE oscillator:
   a) Set clock control register RCC_CR[16] = 1

2. Configure PA8 pin to Clock output function
   a) Select GPIO alternate function to MCO (= 0x0)
   b) Select GPIO speed to Very high frequency (= 0x3)

3. Select HSE as output clock with no division factor:
   a) Clock configuration register RCC_CFRG[30:24] = 0b000_0100

Load capacitance setting

The RCC_HSECR[13:8] register drives the load capacitance.

The proposed procedure uses the three push-button available on the Nucleo68 board to modify the register value:

- Pushing SW1 button increases this value by 1.
- Pushing SW2 button saves it in the nonvolatile memory.
- Pushing SW3 button decreases it by 1.
  - Initial value is set to 0 after reset, it cannot be increased above 0x3F (maximum load capacitance) and cannot be decreased below 0x0 (minimum load capacitance). After each action, the frequency has to be measured.

The next sequence is required for each tested value:

1. Disable the HSE clock:
   - Clock control register RCC_CR[16] = 0

2. Unlock RCC_HSECR register:
   - WRITE_REG(RCC_HSECR, 0xCAFECAFE);

3. Write the six bits of load capacitance in RCC_HSECR[13:8]

4. Turn on the HSE oscillator:
   - Clock control register RCC_CR[16] = 1

Other fields of the register remain unchanged in this procedure and keep their initial value:

- HSE current control (HSEGMC = RCC_HSECR[6:4]) is set to 0x3 → current max limit 1.13 mA / V.
- HSE sense amplifier threshold (HSES = RCC_HSECR[3]) is set to 0 → HSE bias current factor 1/2
3.2.2 Software implementation

Project configurations

Two project configurations are available in the package, one for the calibration procedure (STM32WBxx_Nucleo_Set_Calibration), another one to test the stored value (STM32WBxx_Nucleo_Test_Calibration). This last configuration is given as an implementation example of the HSE clock initialization in RF applications.

The firmware is built on the STM32WB HAL drivers.
1. STM32WBxx_Nucleo_Set_Calibration: the device is programmed to:
   – Send the HSE clock on the PA8 pin.
   – Modify and set the load capacitance value when push-buttons SW1 and SW3 are actioned.
   – Store the load capacitance value together with the 48 bits of additional data (Bluetooth device address) in the OTP or the selected flash memory area when SW2 button is pushed.
2. STM32WBxx_Nucleo_Test_Calibration: configuration to test the actual HSE settings:
   – Configure the HSE clock and output it on PA8 pin.
   – Fetch the load capacitance value from the OTP/flash memory area.
   – Program RCC_HSECR register accordingly.

Storage in OTP (one-time-programmable) bytes

Load capacitance value is included in a 64-bit structure. Each OTP structure type is indicated by its index (one byte). The index used for the structure in this application note is 0. Six bytes remain to store additional data like MAC, Bluetooth device address or crypto key.

```c
typedef __packed struct
{
    uint8_t  additional_data[6]; /* 48 bits */
    uint8_t  hse_tuning; /* Load capacitance value */
    uint8_t  index; /* structure index ==0x00*/
} OTP_BT_t;
```
The configuration phase usually is not repeated, but there are cases when it must be overwritten. When using OTP bytes, the current configuration cannot be removed, hence the new one is placed at the next free double-word slot (see Figure 7).

**Figure 7. Configuration store in OTP bytes**

<table>
<thead>
<tr>
<th>OTP_data Idx = 0</th>
<th>OTP_data Idx = n</th>
<th>OTP_data Idx = 0</th>
<th>OTP_data Idx = m</th>
<th>0xFFFFFFFF_FFFFFFFF</th>
</tr>
</thead>
</table>

When the calibration phase has been done, the application initialization phase must retrieve the load capacitance (and other additional data) from this OTP area. The value retained is then the last one with the right index.

### 3.2.3 Scripts

Two batch scripts are provided to run each firmware configuration:

1. **STM32WBxx_Nucleo_Set_HSE_Calibration_OTP.bat**
2. **STM32WBxx_Nucleo_Test_HSE_Calibration_OTP.bat**

These scripts call the STM32CubeProgrammer in command-line mode, and the path to the tool must be set accordingly: `SET CLI="C:\Program Files (x86)\STMicroelectronics\STM32Cube\STM32CubeProgrammer\bin\STM32_Programmer_CLI.exe`.

The binary or hex file of the configuration must be set also (example for Set_Calibration)

1. For Keil®:
   
   `SET HEXFILE=STM32WBxx_Nucleo\STM32WBxx_Nucleo_Set_Calibration.hex`

2. For IAR™:
   
   `SET HEXFILE=STM32WBxx_Nucleo_Set_Calibration\Exe\STM32WBxx_Nucleo_Set_Calibration.hex`

3. For STM32CubeIDE:
   
   `SET HEXFILE=STM32WBxx_Nucleo_Set_Calibration\Debug\STM32WBxx_Nucleo_Set_Calibration.hex`

The 48 bits of additional data (last parameter) are transmitted to the device through these scripts. They are stored inside the SRAM and read by the FW.

```
%CLI% -c port=swd -w32 0x2002FFF0 0x33445566
%CLI% -c port=swd -w32 0x2002FFF4 0x00001122
```
4 Manual frequency trimming procedure example for the STM32WL Series

The firmware associated to this application note is available as an STM32Cube Expansion Package (X-CUBE-CLKTRIM_vx.y\Projects\Nucleo-WL55JC\RCC_HSE_Calib_SingleCore).

Note: The trimmed NUCLEO-WL55JC board needs to be configured to use the on-board crystal as HSE instead of the TCXO (which adjusts its frequency autonomously, according to the temperature). For details refer to UM2592, available on www.st.com.

4.1 Procedure description

The procedure consists in measuring the HSE clock generated inside the device from the external crystal. This clock is output on pin PA8 and is measured by a precision frequency meter.

Note: An external reference is mandatory since no such accurate internal one exists in the device.

A step-by-step tuning of the load capacitance is performed to reach the best accuracy of the HSE clock. The IN and OUT banks load capacitance values are then stored in a nonvolatile location of the device, either a dedicated area of the user flash memory or in the OTP programming area.

Flash memory or OTP programming is done with a double-word granularity (64 bits). To save OTP bytes (1 K in the STM32WL Series), the IN and OUT load capacitance values, each one on six bits, can be appended to a 64-bit wide structure with other personalization data (such as device address, product specific code, key).

This procedure can be done several times, only the last setup is active.

Once the procedure is completed, the active load capacitance value can be retrieved at startup (in the clock configuration function), and the HSE configuration register set accordingly.

4.2 Implementation

The procedure runs in SRAM, so it can be executed on an already programmed device without modifying the flash memory content.
4.2.1 Hardware setup

Figure 8 shows the manual calibration procedure for a STM32WL Series Nucleo board.

A precision frequency meter (better than 0.1 ppm) must be connected to pin PA8/MCO and set to detect a 32 MHz square wave 3.3 V peak to peak signal.

Note: Standard oscilloscopes are not enough accurate for this kind of measurement.

Boot from SRAM

Boot selection can be done through the BOOT0 pin and nBOOT1 bit in the user options (FLASH_OPTR).

The boot from SRAM configuration is set by both BOOT0 = 1 and nBOOT1 = 0 conditions, nBOOT1 is set only by option bit FLASH_OPTR[23].

BOOT0 can be selected

- through value of pin PH3 at startup if option bit nSWBOOT0 = 1 (FLASH_OPTR[26] = 1), see the option byte panel in Figure 9
- through option bit value nBOOT0 if option bit nSWBOOT0 = 0 (FLASH_OPTR[26] = 0), see the option byte panel in Figure 10

Option bits can be selected through STM32CubeProgrammer.
Figure 9. OB configuration to boot from SRAM with BOOT0 value driven by PH3 pin

<table>
<thead>
<tr>
<th>Name</th>
<th>Value</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>nBOOT0</td>
<td></td>
<td>Unchecked: nBOOT0=0</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: nBOOT0=1</td>
</tr>
<tr>
<td>nBOOT1</td>
<td></td>
<td>Unchecked: Boot from code area if BOOT0=0 otherwise system Flash</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Boot from code area if BOOT0=1 otherwise embedded SRAM</td>
</tr>
<tr>
<td>nSWBOOT0</td>
<td></td>
<td>Unchecked: BOOT0 taken from the option bit nBOOT0</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: BOOT0 taken from PH3/BOOT0 pin</td>
</tr>
<tr>
<td>SKRST</td>
<td></td>
<td>Unchecked: SKRAM erased when a system reset occurs</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: SKRAM is not erased when a system reset occurs</td>
</tr>
<tr>
<td>nRAM2PE</td>
<td></td>
<td>Unchecked: SKRAM parity check enable</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: SKRAM parity check disable</td>
</tr>
<tr>
<td>nRST_STOP</td>
<td></td>
<td>Unchecked: Reset generated when entering the Stop mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: No reset generated when entering the Stop mode</td>
</tr>
<tr>
<td>nRST_STDBY</td>
<td></td>
<td>Unchecked: Reset generated when entering the Standby mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: No reset generated when entering the Standby mode</td>
</tr>
<tr>
<td>nRSTSHDW</td>
<td></td>
<td>Unchecked: Reset generated when entering the Shutdown mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: No reset generated when entering the Shutdown mode</td>
</tr>
<tr>
<td>WWDGSDW</td>
<td></td>
<td>Unchecked: Hardware window watchdog</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Software window watchdog</td>
</tr>
<tr>
<td>SWDOSTDBY</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Standby mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Independent watchdog counter running in Standby mode</td>
</tr>
<tr>
<td>IWDOSTOP</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Standby mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Independent watchdog counter running in Standby mode</td>
</tr>
<tr>
<td>IWDOGW</td>
<td></td>
<td>Unchecked: Hardware independent watchdog</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Software independent watchdog</td>
</tr>
<tr>
<td>C1BOOTLOCK</td>
<td></td>
<td>Unchecked: CPU1 CM4 Unique Boot entry lock disabled</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: CPU1 CM4 Unique Boot entry lock enabled</td>
</tr>
<tr>
<td>C2BOOTLOCK</td>
<td></td>
<td>Unchecked: CPU2 CM0+ Unique Boot entry lock disabled</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: CPU2 CM0+ Unique Boot entry lock enabled</td>
</tr>
<tr>
<td>IPCDDBA</td>
<td>0x3ff</td>
<td>IPCC mailbox data buffer base address</td>
</tr>
</tbody>
</table>

Figure 10. OB configuration to boot from SRAM with BOOT0 value driven by option bit nBOOT0

<table>
<thead>
<tr>
<th>Name</th>
<th>Value</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>nBOOT0</td>
<td></td>
<td>Unchecked: nBOOT0=0</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: nBOOT0=1</td>
</tr>
<tr>
<td>nBOOT1</td>
<td></td>
<td>Unchecked: Boot from code area if BOOT0=0 otherwise system Flash</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Boot from code area if BOOT0=1 otherwise embedded SRAM</td>
</tr>
<tr>
<td>nSWBOOT0</td>
<td></td>
<td>Unchecked: BOOT0 taken from the option bit nBOOT0</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: BOOT0 taken from PH3/BOOT0 pin</td>
</tr>
<tr>
<td>SKRST</td>
<td></td>
<td>Unchecked: SKRAM erased when a system reset occurs</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: SKRAM is not erased when a system reset occurs</td>
</tr>
<tr>
<td>nRAM2PE</td>
<td></td>
<td>Unchecked: SKRAM parity check enable</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: SKRAM parity check disable</td>
</tr>
<tr>
<td>nRST_STOP</td>
<td></td>
<td>Unchecked: Reset generated when entering the Stop mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: No reset generated when entering the Stop mode</td>
</tr>
<tr>
<td>nRST_STDBY</td>
<td></td>
<td>Unchecked: Reset generated when entering the Standby mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: No reset generated when entering the Standby mode</td>
</tr>
<tr>
<td>nRSTSHDW</td>
<td></td>
<td>Unchecked: Reset generated when entering the Shutdown mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: No reset generated when entering the Shutdown mode</td>
</tr>
<tr>
<td>WWDGSDW</td>
<td></td>
<td>Unchecked: Hardware window watchdog</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Software window watchdog</td>
</tr>
<tr>
<td>SWDOSTDBY</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Standby mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Independent watchdog counter running in Standby mode</td>
</tr>
<tr>
<td>IWDOSTOP</td>
<td></td>
<td>Unchecked: Independent watchdog counter frozen in Standby mode</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Independent watchdog counter running in Standby mode</td>
</tr>
<tr>
<td>IWDOGW</td>
<td></td>
<td>Unchecked: Hardware independent watchdog</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: Software independent watchdog</td>
</tr>
<tr>
<td>C1BOOTLOCK</td>
<td></td>
<td>Unchecked: CPU1 CM4 Unique Boot entry lock disabled</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: CPU1 CM4 Unique Boot entry lock enabled</td>
</tr>
<tr>
<td>C2BOOTLOCK</td>
<td></td>
<td>Unchecked: CPU2 CM0+ Unique Boot entry lock disabled</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Checked: CPU2 CM0+ Unique Boot entry lock enabled</td>
</tr>
<tr>
<td>IPCDDBA</td>
<td>0x3ff</td>
<td>IPCC mailbox data buffer base address</td>
</tr>
</tbody>
</table>
Clock output

HSE clock is output on pin PA8 (MCO), available on connectors CN10/16. PA8 configuration is performed by the firmware. Frequency meter probe is connected to this connector and ground can be taken from connector CN3 or CN4. According to the type of frequency meter used, it can be needed to use AC coupling instead of DC.

The next sequence is required to output the HSE on the MCO pin.
1. Turn on the HSE oscillator:
   a) Set clock control register RCC_CR[16]=1
2. Configure PA8 pin to clock output function:
   a) Select GPIO alternate function to MCO (= 0x0)
   b) Select GPIO speed to Very high frequency (= 0x3)
3. Select HSE as output clock with no division factor:
   a) Clock configuration register RCC_CFGR[30:24] = 0b000_0100

Load capacitance setting

The SUBGHZ_HSEINTRIMR[5:0] bits set the capacitance for bank IN.

The SUBGHZ_HSEOUTTRIMR[5:0] bits set the capacitance for bank OUT.

The proposed procedure uses the three push-buttons available on the Nucleo board to modify the registers value:
- After startup, each push of SW1 or SW3 respectively increases the value of SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR by 1.
- One short push on SW2 changes the variations direction. For example if we push one time SW2 after startup, then each SW1 / SW3 push respectively decreases the value of SUBGHZ_HSEINTRIMR / SUBGHZ_HSEOUTTRIMR by 1. Another SW2 push sets back an increasing variations direction, another one sets back a decreasing variations direction, and so on.
- Pushing SW2 for two seconds (the three Nucleo LEDs blink at the same time when the push has been taken into account) stores the parameters in memory (OTP or flash memory according to constants defined by the user).

For these two registers the initial value is set to 0x12 (20.3 pF) after reset. It cannot be increased above 0x2F (maximum load capacitance 33.4 pF), and cannot be decreased below 0x0 (minimum load capacitance 11.3 pF). After each action, the frequency must be measured.
The next sequence is required for each tested value:

1. Enter the sub-GHz radio in standby with HSE32 mode:
   - sends the command code 0x80 to the sub-GHz radio SPI interface with no parameters (set the parameter to 0 by default).

2. Write the six bits of load capacitance in SUBGHZ_HSEINTRIMR[5:0] or SUBGHZ_HSEOUTTRIMR[5:0]:
   - sends the command code 0x0D (write register command) to the sub-GHz radio SPI interface followed by the register address (0x0911 for SUBGHZ_HSEINTRIMR and 0x0912 for SUBGHZ_HSEOUTTRIMR) and the value they have to take.

3. Enter the sub-GHz radio in FS (frequency synthesis) mode (to exit standby mode):
   - sends the command code 0xC1 to the sub-GHz radio SPI interface with no parameters (set the parameter to 0 by default).

### 4.2.2 Software implementation

#### Project configurations

Two project configurations are available in the package, one for the calibration procedure (determination called RCC_HSE_Calib_SingleCore) and another to test the stored value (called RCC_HSE_Calib_SingleCore_Test). The latter configuration is given as an implementation example of the HSE clock initialization in RF applications.

The firmware is built on the STM32WL HAL drivers.

1. RCC_HSE_Calib_SingleCore: the device is programmed to:
   - a) Send the HSE clock on the PA8 pin.
   - b) Modify and set the IN and OUT load capacitance values when push-buttons SW1 and SW3 are actioned (short push on SW2 changes the variations direction).
   - c) Store the load capacitance value together with the 40 bits of additional data (Bluetooth device address) in the OTP or the selected flash memory area when SW2 is pushed for two seconds.

2. RCC_HSE_Calib_SingleCore_Test, a configuration to test the saved HSE settings:
   - a) Configure the HSE clock and output it on PA8 pin.
   - b) Fetch the IN and OUT load capacitance values from the OTP/flash memory area.
   - c) Program SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR registers accordingly.

#### Storage in OTP bytes

Load capacitance values are included in a 64-bit structure. Each OTP structure type is indicated by its index (one byte). The index used for the structure in this application note is 0. Five bytes remain to store additional data like device address or crypto key.

```c
typedef __packed struct
{
  uint8_t additional_data[5]; /* 48 bits */
  uint8_t hse_tuning_in; /* IN bank load capacitance value */
  uint8_t hse_tuning_out; /* OUT bank load capacitance value */
  uint8_t index; /* structure index ==0x00*/
} OTP_BT_t
```
Even if the configuration phase is not supposed to be repeated, there may be some case where it should be overwritten. When using OTP bytes, the current configuration cannot be removed, so the new one is placed at the next free double-word slot (see Figure 7).

When the calibration phase has been done, the application initialization phase must retrieve the IN and OUT load capacitances (and other additional data) from this OTP area. The values retained are the last ones with the right index.

### 4.2.3 Scripts

Two batch scripts are provided to run each firmware configuration:

- `RCC_HSE_Calib_SingleCore_OTP.bat`
- `RCC_HSE_Calib_SingleCore_Test_OTP.bat`

These scripts call the STM32CubeProgrammer command-line interface, and the path to the tool must be set accordingly:

```plaintext
SET CLI="C:\Program Files (x86)\STMicroelectronics\STM32Cube\STM32CubeProgrammer\bin\STM32_Programmer_CLI.exe"
```

The binary or hex file of the configuration must be set also

For IAR™:

```plaintext
SET BINFILE="RCC_HSE_Calib_SingleCore\Exe\RCC_HSE_Calib_SingleCore.bin"
```

For Keil®:

```plaintext
SET HEXFILE="RCC_HSE_Calib_SingleCore\Exe\RCC_HSE_Calib_SingleCore.hex"
```

The 40 bits of additional data (last parameter) are transmitted to the device through these scripts. They are stored inside the SRAM and read by the firmware.

```plaintext
STM32_Programmer_CLI.exe -c port=swd -w32 0x20006FF0 0x22334455
STM32_Programmer_CLI.exe -c port=swd -w32 0x20006FF4 0x00000011
```
5 Automatic frequency trimming procedure example for the STM32WB Series

The firmware and scripts associated to this document are available as an STM32Cube Expansion Package (X-CUBE-CLKTRIM_vx.y\Projects\P-NUCLEO-WB55.Nucleo\RCC_HSE_AutoCalib).

5.1 Procedure description

The procedure consists in measuring the HSE clock generated inside the device from the external crystal. The measure is done internally to the STM32 system and is based on an accurate external 16 MHz clock reference provided by the user on PA9.

Note: An external reference is mandatory since no such accurate one is integrated in the device.

An automatic tuning of the load capacitance is performed by a specific STM32 application to reach the best accuracy of the HSE clock. The load capacitance value found is then stored in a nonvolatile location of the device, in a dedicated area of the user flash memory or of the OTP.

Flash memory or OTP programming is done with a double-word granularity (64 bits). To save OTP bytes (1 K in the STM32WB Series), the load capacitance value on six bits can be appended to a 64-bit wide structure with other personalization data (such as the Bluetooth device address, the MAC short address, the product specific code, the key).

This procedure can be done several times, only the latest setup is active.

Once the procedure is completed, the active load capacitance value can be retrieved at startup (in the clock configuration function) and the HSE configuration register set accordingly.
5.2 Implementation

5.2.1 Hardware setup

Figure 11 shows the automatic calibration procedure for a STM32WB Series Nucleo-68 board.

Figure 11. Automatic calibration overview - STM32WB Series

A precision clock generator (better than 0.1 ppm) must be connected to pin PA9/TIM1_CH2, and set to generate a 16 MHz, 3.3 Vpp square wave. To see how to configure the board so as to boot from SRAM refer to Section 3.2.1: Hardware setup.

Note: A standard signal generator does not give enough accuracy for this application.

Hardware connections principle

Two timers (TIMER1 and TIMER2) are used by the MCU to exploit the external reference clock and thus to measure and tune the HSE frequency.

TIMER1 is clocked by the 16 MHz precision external reference clock and generate a PWM signal low during an OFF time (fixed to 16 ms) and high during a REF time (100 or 1000 ms, depending on the stage of the calibration procedure).

This PWM signal is used to enable TIMER2 counter when high.

TIMER2 is clocked by HSE/2 output on MCO pin.

Then, after one PWM signal period, TIMER2 counter corresponds to the number of HSE/2 periods elapsed during REF time.

This value can be compared to the expected value to adjust the load capacitance conditioning HSE frequency.

Note: OFF time is needed to temporize and wait for HSE stabilization when several HSE measurements are done in sequence.
Figure 12 illustrates the connections between the elements involved in the procedure.

**Figure 12. Procedure implementation**

### TIMER1 configuration

TIM1 is configured to be clocked by a 16 MHz external signal provided on PA9. PA9 is associated to the TIM1 CH2, which provides the TI2 (trigger input 2) input. So TI2 has to be chosen as TIM1 clock source.

- SMS bits of TIM1_SMCR register = b0111 (external clock mode 1)
- TS bits of TIM1_SMCR register = b00110 (trigger input = TI2, filter and polarity for the input also must be set).

TIM1 has to generate a PWM signal low during OFF time and high during REF time.

For this purpose, TIM1 CH3 is configured in PWM mode 2 (low then high cycles) with a prescaler of 16000 to get a 1 ms granularity (APB2 frequency is configured to be 16 MHz and 16 MHz / 16000 = 1000 Hz). The period is set to REF time + OFF time - 1 and the pulse duration to OFF time to get the desired signal (REF and OFF times in milliseconds).

- TIM1_ARR register = 0x3E7F (prescaler = 16000)
- TIM1_PSC register = REF time + OFF time - 1 (period)
- OC3M bits of TIM1_CCMR2 register = b111 (PWM mode 2)
- TIM1_CCR3 register = OFF time (pulse for channel 3)

Finally, TIM1 has to be set in master mode OC3REF so that its TRGO (trigger output) relays the PWM signal generated by its CHANNEL 3.

- MMS bits of TIM1_CR2 register = b110 (OC3REF master mode).

### TIMER2 configuration

TIM2 needs to be clocked by HSE/2.

For this purpose we output HSE/2 on MCO pin PA8:

- RCC_CFGR[30:24] = b001_0100 (HSE as MCO output with a division factor of 2).

And PA8 is linked externally to PA5, corresponding to TIM2 ETR (external trigger) input.
Then, external clock mode 2 (counter clocked by any active edge on the ETRF signal) must be chosen as TIM2 clock source.

- ECE bits in TIM2_SMCR = b1

TIM2 CH2 is configured as a simple time base to count the HSE/2 periods. The time base period is set to its maximum value 0xFFFFFFFF to be sure HSE/2 measurement does not overflow.

- TIM2_ARR register = 0 (prescaler = 0)
- TIM2_PSC register = 0xFFFFFFFF (period)

Finally, TIM2 has to be set in GATED slave mode with ITR0 as trigger input. Since TIM2 ITR0 and TIM1 TRGO are connected, the GATED mode enables the TIM2 CH2 counter only when the TIM1 CH3 PWM signal displayed on TRGO is high.

- SMS bits in TIM2_SMCR register = b0101 (GATED mode)
- TS bits in TIM2_SMCR register = b00000 (ITR0 as trigger input)

### 5.2.2 Software implementation

#### Firmware tuning algorithm principle

The TIMER links presented above allows to count the number of HSE/2 periods elapsed during REF time with the external reference clock precision.

The HSE_Measurement function of the firmware provided with this AN allows to get this number of periods by launching one TIM1 CH3 PWM cycle and returning the value of the TIM2 CH2 counter.

The function HSE_Tuning exploits HSE_Measurement to tune HSE, using dichotomy logic to find the best load capacitance value for HSE to be the closest to 32 MHz.

The tuning parameter that sets the load capacitance can take values from 0 to 63. So the function starts by setting it to 32 (RCC_HSECR[13:8] = HSETUNE = 32). Then, it makes an HSE/2 measurement.

If the frequency measured (calculated thanks to the number of periods returned by HSE_Measurement) is above 16 MHz, the function increases HSETUNE to lower the frequency. If it is below, it decreases it to increase the frequency.

The variations of HSETUNE are done with a step starting with a value of 16 when HSETUNE is 32. After each measurement, this step is divided by two to calculate the new HSETUNE value to test.

So far, the measurements duration is 100 ms. When the step value reaches a value of 1 and that the load capacitance approaches the best value, the duration is set to 1000 ms to be even more precise.

When the step reaches 1, if the measured HSE/2 frequency is below 16 MHz, the function decrements HSETUNE and makes new measurements and adjustments until the measured frequency exceeds 16 MHz. Then the function takes the HSETUNE value between the one above 16 MHz and the last one below with the best HSE precision.

The reasoning is the same if the last 100 ms measurement (the last one before the step has reached 1) is above 16 MHz.

Finally, the HSETUNE value found is saved in a nonvolatile memory.
Other fields of the RCC_HSECR register remain unchanged in this procedure and keep their initial value:

- HSE current control (HSEGMC = RCC_HSECR[6:4]) is set to 0x3 → current max limit 1.13 mA/V
- HSE sense amplifier threshold (HSES = RCC_HSECR[3]) is set to 0 → HSE bias current factor 1/2

**Firmware configurations**

The constant STORE_ADDRESS in hse_trimming.h allows the user to choose to save HSETUNE in OTP (STORE_ADDRESS = 0xFFFFF7000U) or flash memory (STORE_ADDRESS = 0x080A0000 for example).

Two project configurations are available in the package, one (RCC_HSE_AutoCalib) for the calibration procedure, another one (RCC_HSE_AutoCalib_Test) to test the stored value. This last configuration is given as an implementation example of the HSE clock initialization in RF applications.

*Note: Under STM32CubeIDE, the two projects are called, respectively, STM32WBxx_Nucleo_Set_AutoCalibration, STM32WBxx_Nucleo_Test_AutoCalibration.*

The firmware is built on the STM32WB HAL drivers.

- **RCC_HSE_AutoCalib**: the device is programmed to:
  - send the HSE clock on the PA8 pin, configure the timers and exploit the external clock source
  - modify and set the load capacitance value following the trimming algorithm presented before
  - store the load capacitance value together with the 48 bits of additional data (Bluetooth device address) in the OTP memory or in the selected flash memory area.

- **RCC_HSE_AutoCalib_Test**: the device is programmed to test the actual HSE setting:
  - configure the HSE clock and output it on PA8 pin
  - fetch the load capacitance value from the OTP/flash memory area
  - program RCC_HSECR register accordingly.

**Storage in OTP bytes**

The way to store tuning parameters in OTP memory is the same used for the manual trimming procedure for STM32WB Series (see Section 3.2.2: Software implementation).

### 5.2.3 Scripts

Two batch scripts are provided to run each FW configuration:

1. STM32WBxx_Nucleo_Set_HSE_AutoCalibration_OTP.bat
2. STM32WBxx_Nucleo_Test_HSE_AutoCalibration_OTP.bat

These scripts call the STM32CubeProgrammer in command-line mode, and the path to the tool must be set accordingly: `SET CLI="C:\Program Files (x86)\STMicroelectronics\STM32Cube\STM32CubeProgrammer\bin\STM32_Programmer_CLI.exe"`
The binary or hex file of the configuration must be set also (example for the Set Calibration application):

- for IAR™: `SET HEXFILE="RCC_HSE_AutoCalib\Exe\RCC_HSE_AutoCalib.hex"
- for Keil®: `SET HEXFILE="RCC_HSE_AutoCalib\RCC_HSE_AutoCalib.hex"
- For STM32CubeIDE:
  `SET HEXFILE="STM32WBxx_Nucleo_Set_AutoCalibration\Debug\STM32WBxx_Nucleo_Set_AutoCalibration.hex"

The 48 bits of additional data (last parameter) are transmitted to the device through these scripts. They are stored inside the SRAM and read by the FW.

%CLI% -c port=swd -w32 0x2002FFF0 0x33445566
%CLI% -c port=swd -w32 0x2002FFF4 0x00001122
6 Automatic frequency trimming procedure example for the STM32WL Series

The firmware associated to this document is available as an STM32Cube Expansion Package (X-CUBE-CLKTRIM_vx.y\Projects\NUCLEO-WL55JC\RCC_HSE_AutoCalib_SingleCore).

Note: The trimmed NUCLEO-WL55JC board needs to be configured to use the on-board crystal as HSE instead of the TCXO (which adjusts its frequency autonomously, according to the temperature). For details refer to UM2592, available on www.st.com.

6.1 Procedure description

The procedure consists in measuring the HSE clock generated inside the device from the external crystal. The measure is done internally to the STM32 system and is based on an accurate external 16 MHz clock reference provided by the user on PA9.

Note: An external reference is mandatory since no such accurate internal one exists in the device.

An automatic tuning of the load capacitance is performed by a specific STM32 application to reach the best accuracy of the HSE clock. The load capacitance values are then stored inside a nonvolatile location of the device (a dedicated area of the user flash memory, or in the OTP programming area).

Flash or OTP memory programming is done with a double-word granularity (64 bits). In order to save OTP bytes (1 K in the STM32WL Series), the IN and OUT load capacitance values, each one on 6 bits, can be appended to a 64-bit wide structure with other personalization data (such as device address, product specific code, key).

This procedure can be repeated several times, only the last setup is active.

Once the procedure is completed, the active load capacitance values can be retrieved at startup (in the clock configuration function) and the HSE configuration register set accordingly.
6.2 Implementation

6.2.1 Hardware setup

*Figure 13* shows the automatic HSE calibration procedure for a STM32WL Series Nucleo board.

![Figure 13. Automatic calibration overview - STM32WL Series](image)

A precision clock generator (better than 0.1 ppm) must be connected to pin PA9/TIM1_CH2, and set to generate a 16 MHz, 3.3 Vpp square wave. To see how to configure the board to boot from SRAM refer to *Section 4.2.1: Hardware setup*.

**Note:** A standard signal generator does not give enough accuracy for this application.

**Hardware connections principle**

The ways to establish connections and to implement TIMER1 and TIMER2 are the same than for the automatic trimming procedure for STM32WB Series (see *Section 5.2.1*).

6.2.2 Software implementation

**Firmware tuning algorithm principle**

The TIMER links presented in *Section 5.2.1* allows to count the number of HSE/2 periods elapsed during REF time with the external reference clock precision.

The HSE_Measurement function of the firmware provided with this document can be used to get this number by launching one TIM1 CH3 PWM cycle and returning the value of the TIM2 CH2 counter.

The function HSE_Tuning exploits HSE_Measurement to tune HSE.

It follows a dichotomy logic to find the best load capacitance value for HSE to be the closest to 32 MHz.
The tuning parameters that sets the IN and OUT load capacitances can take values from 0 to 47. So the function starts by setting it both to 24 (SUBGHZ_HSEINTRIMR[5:0] = 24 and SUBGHZ_HSEOUTTRIMR[5:0] = 24). Then, it makes an HSE/2 measurement.

If the frequency measured (calculated thanks to the number of periods returned by HSE_Measurement) is above 16 MHz, the function increases SUBGHZ_HSEINTRIMR to lower the frequency. If it is below, it decreases it to increase the frequency.

The variations of SUBGHZ_HSEINTRIMR are done with a step starting with a value of 12 when SUBGHZ_HSEINTRIMR is 24. After each measurement, this step is divided by two to calculate the new SUBGHZ_HSEINTRIMR value to test.

For each measurement, the parameter tuned is changed. That is to say, a first measurement is done and SUBGHZ_HSEINTRIMR is adjusted, another measurement is done and SUBGHZ_HSEOUTTRIMR is adjusted (and the adjustment principle explained above for SUBGHZ_HSEINTRIMR is followed), then another measurement is done and SUBGHZ_HSEINTRIMR is adjusted again, and so on.

So far, the measurements duration is 100 ms. When, the step values reaches a value of 1 for one of the two parameters (the load capacitance approaches its best value), the duration is set to 1000 ms to be even more precise.

When the step reaches 1, if the HSE/2 frequency measured is below 16 MHz, the function decrements successively SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR, and makes new measurements and adjustments until the HSE/2 frequency measured exceeds 16 MHz. Once above 16 MHz, the function keeps the SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR pair between the one above and the last one below that got the best HSE precision.

The reasoning is the same if the last 100 ms measurement (the last one before the step has reached 1) is above 16 MHz.

Finally, the SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR pair found is saved in a nonvolatile memory.

**Firmware configurations**

The constant STORE_ADDRESS in hse_trimming.h allows the user to choose to save the SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR pair in OTP (STORE_ADDRESS = 0x1FFF7000U) or flash memory (STORE_ADDRESS = 0x0803F800 for example).

Also two project configurations are available in the package, one for the calibration procedure (RCC_HSE_AutoCalib_SingleCore), and another one to test the stored value (RCC_HSE_AutoCalib_SingleCore_Test). This last configuration is given as an implementation example of the HSE clock initialization in RF applications.
The firmware is built on the STM32WL HAL drivers.

- RCC_HSE_AutoCalib_SingleCore: the device is programmed to
  - Send the HSE clock on the PA8 pin, configure the timers and exploit the external clock source
  - Modify and set the IN and OUT load capacitance values following the trimming algorithm presented before
  - Store the IN and OUT load capacitance values together with the 40 bits of additional data in the OTP or in the selected flash memory area.

- RCC_HSE_AutoCalib_SingleCore_Test, to test the actual HSE settings saved:
  - Configure the HSE clock and output it on PA8 pin
  - Fetch the load capacitance value from the OTP/flash memory area
  - Program SUBGHZ_HSEINTRIMR and SUBGHZ_HSEOUTTRIMR registers accordingly

**Storage in OTP**

The way to store tuning parameters in the OTP memory is the same as the one for the manual trimming procedure for STM32WL Series (see Section 4.2.2).

### 6.2.3 Scripts

Two batch scripts are provided to run each FW configuration:

- RCC_HSE_AutoCalib_SingleCore_OTP.bat
- RCC_HSE_AutoCalib_SingleCore_Test_OTP.bat

These scripts call the STM32CubeProgrammer command-line interface, and the path to the tool must be set accordingly:

```plaintext
SET CLI="C:\Program Files (x86)\STMicroelectronics\STM32Cube\STM32CubeProgrammer\bin\STM32_Programmer_CLI.exe"
```

The binary or hex file of the configuration must be set also

- For IAR: SET
  ```plaintext
  BINFILE="RCC_HSE_AutoCalib_SingleCore\Exe\RCC_HSE_AutoCalib_SingleCore.bin"
  ```
- For Keil: SET
  ```plaintext
  HEXFILE="RCC_HSE_AutoCalib_SingleCore\Exe\RCC_HSE_AutoCalib_SingleCore.hex"
  ```

The 40 bits of additional data are transmitted to the device through these scripts. They are stored inside the SRAM and read by the FW.

```plaintext
STM32_Programmer_CLI.exe -c port=swd -w32 0x20006FF0 0x22334455
STM32_Programmer_CLI.exe -c port=swd -w32 0x20006FF4 0x00000011
```
7 STM32CubeMonitor-RF frequency trimming procedure example for the STM32WB Series

The firmware and scripts associated to this document are available as an STM32Cube software expansion (X-CUBE-CLKTRIM_vx.y\Projects\P-NUCLEO-WB55.Nucleo\RCC_HSE_MonitorRFCalib).

Note: STM32CubeMonitor-RF procedure has been developed only for the STM32WB Series since the software does not support the STM32WL Series.

7.1 Procedure description

The procedure is the same as the one detailed in Section 3.1: Procedure description.

7.2 Procedure steps

Details for these steps are given in Section 7.3.2.

This procedure tunes the STM32WB HSE clock using STM32CubeMonitor-RF. Thus, a connection between the two entities must be established.

To allow this connection, two softwares have to be flashed in the STM32WB cores:
- the BLE transparent mode firmware in the Cortex® M4 core
- the BLE stack in the Cortex® M0+ core.

Once the flashing is done, connect the STM32WB to the PC running STM32CubeMonitor-RF.

Go to the Script section in STM32CubeMonitor-RF.

Begin by running mco_output_config.txt to output HSE on pin PA8.

Modify hse_tunning.txt with the HSETUNE tuning parameter to test, and run it.

Measure the frequency of HSE on PA8 and adapt the tuning parameter in hse_tunning.txt if needed, before running it again.

When a satisfying parameter has been found, insert it in trim_param_flash.txt or trim_param_otp.txt, depending on the memory (flash or OTP) where it is saved. Then run the chosen script.

To save in the flash memory the selected page may have to be erased (erase operations are only possible at the page level), using the erase_flash_page.txt script.

Finally, the tuning parameter is saved in a nonvolatile memory.

The C code retrieve_trimming_values gives an example for retrieving the parameter saved in memory.
7.3 Implementation

7.3.1 Hardware setup

Figure 14 shows the STM32CubeMonitor-RF HSE calibration procedure for a STM32WB Series Nucleo-68 board.

A precision frequency meter (better than 0.1 ppm) must be connected to pin PA8/MCO and set to detect a 32 MHz 3.3 V square wave peak to peak signal.

Note: Standard oscilloscopes are not sufficiently accurate for this kind of measurement.

7.3.2 Software and scripts setup

Flashing transparent firmware in the Cortex® M4 core

The BLE transparent mode firmware is available in the STM32Cube_FW_WB package:

- STM32Cube_FW_WB_Vx.y.z\Projects\P-NUCLEO-WB55.Nucleo\Applications\BLE\BLE_TransparentMode

This project can be opened in the user favorite IDE and must run on the Cortex® M4 core.

Flashing BLE stack in the Cortex® M0+ core

The BLE stack is available in the STM32Cube_FW_WB package:

- STM32Cube_FW_WB_Vx.y.z\Projects\STM32WB_Copro_Wireless_Binaries\stm32wb5x_BLE_Stack_fw.bin

The instructions to flash this stack into the Cortex® M0+ core are given in the release notes file: STM32Cube_FW_WB_Vx.y.z\Projects\STM32WB_Copro_Wireless_Binaries\Release_Notes.html
Note: For more information on transparent mode, BLE stack and STM32CubeMonitor-RF relations, refer to UM2288 “STM32CubeMonitor-RF software tool for wireless performance measurements”, available on www.st.com.

**Connecting the product to STM32CubeMonitor-RF**

If a Nucleo board is used simply link it to the PC via USB. If not, the user can communicate with the transparent mode firmware through the USART interface of the MCU, available on pins PB6/RX and PB7/TX.

Note: PB6 and PB7 are used by the ST-Link VCP (Virtual COM Port) on Nucleo boards.

### 7.3.3 Scripts

Note: The scripts presented below are available in the STM32Cube software expansion package (X-CUBE-CLKTRIM_vx.y/Projects/P-NUCLEO-WB55.Nucleo/RCC_HSE_MonitorRFCalib).

**mco_output_config.txt**

No need to modify, run it in STM32CubeMonitor-RF to output HSE on PA8.

**hse_tuning.txt**

This script includes the HSETUNE value to test. This value is the last parameter in the script line below (line 11) and is set to 0x18 for this example.

Send(VS_HCI_C1_WRITE_REGISTER;0x04;0x0000FF00;0x5800009C;0x00001800)

This line updates the HSETUNE bits of the RCC_HSECR register.

To test a HSETUNE tuning parameter, change this value as wanted and run the script in STM32CubeMonitor-RF.

Then, use the frequency meter (HSE measurement on PA8) to evaluate the quality of the HSETUNE value fixed: the closer the HSE frequency to 32 MHZ, the better the HSETUNE quality.

**erase_flash_page.txt**

This script can be used to partially clean the flash memory to save new tuning parameters in an already full page.

Note: The running of the script is not mandatory for the procedure.

The number of the page to erase is the last parameter in the script line below (line 20) and is set to 0xA0 for this example (since the trim_param_flash.txt script delivered saves the parameter at this page).

Send(VS_HCI_C1_WRITE_REGISTER;0x04;0x000007F8;0x58004014;0x00000500)

This line updates the PNB bits of the FLASH_CR register.

Note: To traduce the page number (0x0500 → 0xA0) take into account the mask 0x7F8.

**trim_param_flash.txt**

This script saves a HSETUNE value in flash memory at a given address.
It must be modified with the HSETUNE value found with HSE_tuning.txt to get the best HSE frequency, with other information to complete a 64-bit data and with the address where these data must be saved.

The script lines below (lines 19 to 25) includes the HSETUNE value to modify and other information that can be modified.

As an example, the HSETUNE value saved is 0x1B.

```c
#Write lower BD Address : Company Id = 0xE105 + Board Id = 0x7777 (for example)
Send(VS_HCI_C1_WRITE_REGISTER;0x04;0xFFFFFFFF;0x080A0000;0xE1057777)
Wait(100)
#Write upper BD Address : Id = 0x0 + HSE_Tun = 0x1B(for example) + Upper BD = 0x0080
Send(VS_HCI_C1_WRITE_REGISTER;0x04;0xFFFFFFFF;0x080A0004;0x001B0080)
Wait(100)
```

These lines save in memory a 64-bit data equal to 0x 001B 0080 E105 7777 (64 bits is the size of a flash memory word line).

The other 58 bits apart from the HSETUNE value can be chosen as wanted. For example, they can be the Bluetooth device address.

Moreover, 0x080A0000 corresponds to the address where the 64-bit data is saved (the 32 lower bits at 0x080A0000 and the 32 upper bits at 0x080A0004).

trim_param_otp.txt

trim_param_otp.txt is equivalent to trim_param_flash.txt: the user has to modify the same elements for the script to get the requested behavior.

However, the saving address is not the same as OPT and flash memory are mapped at different addresses in the STM32WB microcontrollers. In the delivered script, the address is close to the beginning of the OTP memory: 0x1FFF7008 and 0x1FFF700C.

### 7.3.4 C code

retrieve_trimming_values.c

This C code is given as an example of implementation for the HSE clock initialization procedure for RF applications when tuning parameters are saved in OTP memory.

It gathers:

- Two constants, CFG_OTP_BASE_ADDRESS and CFG_OTP_END_ADDRESS, localizing the beginning and the ending of the OTP memory.
- The structure OTP_ID0_t representing the 64-bit data saved in memory by trim_param_otp.txt.
- The OTP_Read function that seeks the most recent 64-bit data saved in OTP memory with a 0 ID (0 has been chosen in this application note as the index for HSETUNE data in OTP memory).
- The Config_HSE function that exploits OTP_Read to find the most recent HSETUNE value in OTP memory so as to set the HSETUNE bits in the RCC_HSECR register and to get a satisfying HSE frequency.
Note: The same code can be used for flash memory by changing the two constant values with flash memory addresses.
8  HSE startup optimization for the STM32WB Series

The HSE startup time influences the timings and consumption of an application. Thanks to the HSEGMC and HSES bits in the HSECR register of the STM32WB Series products, it is possible to find the best balance between startup reliability and consumption:

- a higher HSEGMC value results in a shorter startup time, a lower HSEGMC value reduces the current consumption.
- HSES does not modify the consumption but shortens the startup time by a dozen of microseconds when set.

To do this adjustment the following procedure can be followed:

The first condition is that the crystal ESR (equivalent series resistance) must be lower than the maximum value defined in the product datasheet. The minimal transconductance $g_{mcrit}$ of the implemented oscillator must then be determined, computing it from the parameters of the oscillation-loop passive components.

Assuming $CL1 = CL2$, and that the crystal sees on its pads the $CL$ value given by the crystal manufacturer (see Figure 1), $g_{mcrit} = 4 \times ESR \times \left(2 \times \pi \times F\right)^2 \times (C_0 + CL)^2$, where:

- $C_0$ is the crystal shunt capacitance
- $CL$ is the crystal nominal load capacitance
- $F$ is the crystal nominal oscillation frequency

Throughout this procedure, the HSEGMC value must stay above $g_{mcrit}$ (see AN2867 for further details).

1. Set HSES to 1 for a higher comparison threshold (3/4). This higher threshold reduces the time between HSEON = 1 and HSERDY = 1 (startup time).
2. Set HSEGMC to its maximum value (111), and check that the oscillator starts up correctly by putting HSEON = 1, and observing HSERDY also getting to 1 after the startup time. If successful, this configuration corresponds to the shortest startup time the application can achieve.
3. If HSERDY is not triggered with HSES set and HSEGMC at its maximum, decrease HSEGMC until it does. Beware that the HSEGMC successive $Gm$ values are not linear with its binary values, e.g: $b011$ is 1.13 mA/V and $b100$ is 0.61 mA/V (see the reference manual for details). In fact, HSEGMC most significant bit distinguishes two value ranges. Also, when decreasing HSEGMC, its value must not be set below the $g_{mcrit}$ value computed during the first step.
4. If all HSEGMC values have been tested without a successful startup, HSES must be reset, and each HSEGMC value tested again, beginning by its highest value, and without going below $g_{mcrit}$.
5. The procedure ends when a configuration triggers HSERDY: the startup phase has been successful.

If all possible configurations fail, choose another crystal.

After going through this procedure, a (HSEGMC, HSES) combination is found, corresponding to the shortest startup time that the oscillator can achieve. If the startup time is not a problem for the application, decrease HSEGMC further, to get a lower consumption. Remember to stay above $g_{mcrit}$, and to verify that HSERDY is raised after HSEON being set, which indicates a successful startup.
The following software method is proposed to measure the startup duration obtained:

1. Set the (HSEGMC, HSES) combination to test.
2. Configure a timer or the clock cycles counter feature of the DWT peripheral for a measurement in the \( \mu \)s range.
3. Launch this measurement before setting HSEON.
4. Set HSEON and wait for HSERDY to be raised before stopping the measurement.
5. The counter value gives an approximation of the startup phase duration.

*Note:* The correct order to configure HSECR is to begin by adjusting HSEGMC and HSES to check if it starts successfully. The tuning of the HSE frequency with HSETUNE comes as second step.
9 Conclusion

RF applications require a very accurate clock, to ensure best performance. The RF clock is derived from an external crystal, and the frequency fine tuning is obtained by setting the right load capacitance at crystal pins.

STM32 wireless MCUs introduce a very efficient architecture with internal capacitances setting, removing the need for extra components on PCB, and lightening the constraints on the crystal performance.

For the products of the STM32WB Series another setting lets the user define the best balance between oscillator startup time duration and consumption, depending upon the application.
# Revision history

Table 6. Document revision history

<table>
<thead>
<tr>
<th>Date</th>
<th>Revision</th>
<th>Changes</th>
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</thead>
<tbody>
<tr>
<td>27-Sep-2017</td>
<td>1</td>
<td>Initial release.</td>
</tr>
</tbody>
</table>
| 14-Nov-2017     | 2        | Updated:  
|                 |          | – Section 3.2.2: Software implementation  
|                 |          | – Section 3.2.3: Scripts |
| 21-Feb-2019     | 3        | Changed document classification, from ST restricted to Public.  
|                 |          | Updated Section 1: HSE oscillator.  
|                 |          | Minor text edits across the whole document. |
|                 |          | Updated Section 1: HSE oscillator, Section 1.2: STM32 wireless MCUs architecture, Section 1.3: HSE configuration parameters - STM32WB Series, Section 1.6: Crystal references, Section 3: Manual frequency trimming procedure example for the STM32WB Series, Load capacitance setting and Project configurations.  
|                 |          | Added Section 1.4: HSE configuration parameters - STM32WL Series, Section 2: Trimming methods comparison, Section 5: Automatic frequency trimming procedure example for the STM32WB Series and Section 7: STM32CubeMonitor-RF frequency trimming procedure example for the STM32WB Series.  
|                 |          | Updated Table 3: Crystal specifications.  
|                 |          | Minor text edits across the whole document. |
| 04-Feb-2020     | 5        | Updated Introduction. |
| 27-Apr-2020     | 6        | Updated Section 1: HSE oscillator, Section 1.5: Board implementation, Section 1.6: Crystal references and Section 3: Manual frequency trimming procedure example for the STM32WB Series.  
|                 |          | Added Section 1.7: Tuning in production.  
|                 |          | Updated Table 1: Carrier accuracy requirement for RF protocols.  
|                 |          | Minor text edits across the whole document. |
| 26-May-2020     | 7        | Added Note: in Section 2: Trimming methods comparison. |
Updated Introduction, Section 1.3: HSE configuration parameters - STM32WB Series, Section 1.7: Tuning in production, Section 3: Manual frequency trimming procedure example for the STM32WB Series, Section 3.2.1: Hardware setup, Section 3.2.3: Scripts, Section 5: Automatic frequency trimming procedure example for the STM32WB Series, Section 5.2.1: Hardware setup, Firmware configurations, Section 5.2.3: Scripts, Section 7: STM32CubeMonitor-RF frequency trimming procedure example for the STM32WB Series, Section 7.3.2: Software and scripts setup and Section 7.3.3: Scripts. Added footnotes to Table 4: Trimming methods and Table 5: Comparison of trimming methods.

Updated Figure 5: OB configuration to boot from SRAM with BOOT0 value driven by PH3 pin, Figure 6: OB configuration to boot from SRAM with BOOT0 value driven by option bit nBOOT0, Figure 11: Automatic calibration overview - STM32WB Series and Figure 14: STM32CubeMonitor-RF calibration overview - STM32WB Series.

Introduced STM32WL Series, hence updated Introduction and added Section 4: Manual frequency trimming procedure example for the STM32WL Series, Section 6: Automatic frequency trimming procedure example for the STM32WL Series and their subsections.

Updated document title, Introduction, Section 1: HSE oscillator, and Section 9: Conclusion. Added Section 8: HSE startup optimization for the STM32WB Series. Minor text edits across the whole document.

Updated Section 1.1: Crystal oscillator, Current control: HSEGMC[2:0] and Section 8: HSE startup optimization for the STM32WB Series. Updated Table 2: Oscillator pin numbers for the STM32WB Series. Minor text edits across the whole document.
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